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Microsemi

Power Matters[™]

30.00 W

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Overview Diagrams

Diagrains

Electrical Rating	Syml	bol	Min		Тур	Max	Unit
Collector to Emitter Saturation Voltage	V _{CE(sat)}					1.50	V
DC Current Gain	HFE		40.00				
Maximum Electrical Rating		Symb	ool	Min	Тур	Max	Unit
Maximum Electrical Rating Breakdown Voltage, Collector-Base (Emitter Open)		Symb		Min	Тур	Max 75.00	Unit
<u> </u>				Min	Тур		

This part can be found in the following product categories:

Emitter-Base Voltage (Collector Open)

Power Dissipation, Total

- ▶ Discretes ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ PNP Transistor
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